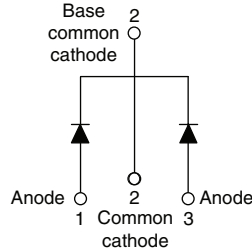


## Ultrafast Rectifier, 20 A FRED Pt™


**TO-220AB**


### FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level


**RoHS\***  
COMPLIANT

### DESCRIPTION/APPLICATIONS

MUR.. series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, dc-to-dc converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

### PRODUCT SUMMARY

$t_{rr}$	25 ns
$I_{F(AV)}$	20 A
$V_R$	200 V

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		200	V
Average rectified forward current	$I_{F(AV)}$	per leg	10	A
		total device	Rated $V_R$ , $T_C = 145\text{ °C}$	
Non-repetitive peak surge current per leg	$I_{FSM}$		100	
Peak repetitive forward current per leg	$I_{FM}$	Rated $V_R$ , square wave, 20 kHz, $T_C = 145\text{ °C}$	20	
Operating junction and storage temperatures	$T_J, T_{Stg}$		- 65 to 175	°C

### ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_R$	$I_R = 100\ \mu\text{A}$	200	-	-	V
Forward voltage	$V_F$	$I_F = 8\text{ A}, T_J = 125\text{ °C}$	-	-	0.85	
		$I_F = 16\text{ A}$	-	-	1.15	
Reverse leakage current	$I_R$	$V_R = V_R\text{ rated}$	-	-	15	$\mu\text{A}$
		$T_J = 150\text{ °C}, V_R = V_R\text{ rated}$	-	-	250	
Junction capacitance	$C_T$	$V_R = 200\text{ V}$	-	55	-	pF
Series inductance	$L_S$	Measured lead to lead 5 mm from package body	-	8.0	-	nH

\* Pb containing terminations are not RoHS compliant, exemptions may apply



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	$t_{rr}$	$I_F = 1.0\text{ A}$ , $di_F/dt = 50\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$	-	-	35	ns
		$I_F = 0.5\text{ A}$ , $I_R = 1.0\text{ A}$ , $I_{REC} = 0.25\text{ A}$	-	-	25	
		$T_J = 25\text{ }^\circ\text{C}$	-	21	-	
		$T_J = 125\text{ }^\circ\text{C}$	-	35	-	
Peak recovery current	$I_{RRM}$	$T_J = 25\text{ }^\circ\text{C}$	-	1.9	-	A
		$T_J = 125\text{ }^\circ\text{C}$	-	4.8	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^\circ\text{C}$	-	25	-	nC
		$T_J = 125\text{ }^\circ\text{C}$	-	78	-	

<b>THERMAL - MECHANICAL SPECIFICATIONS</b>						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	$T_J$ , $T_{Stg}$		- 65	-	175	$^\circ\text{C}$
Thermal resistance, junction to case per leg	$R_{thJC}$		-	-	2.5	$^\circ\text{C}/\text{W}$
Thermal resistance, junction to ambient per leg	$R_{thJA}$		-	-	50	
Thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, flat, smooth and greased	-	0.5	-	
Weight			-	2.0	-	g
			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-220AB	MUR2020CT			

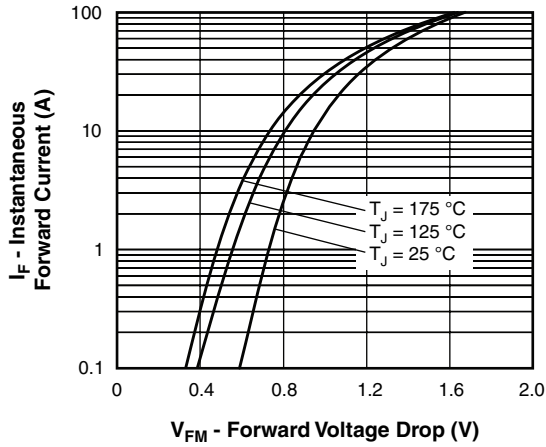


Fig. 1 - Maximum Forward Voltage Drop Characteristics

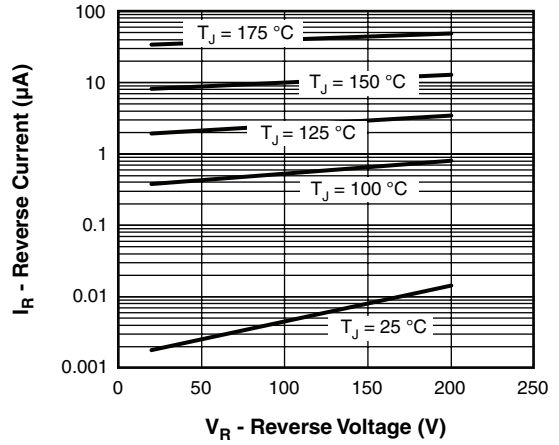


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

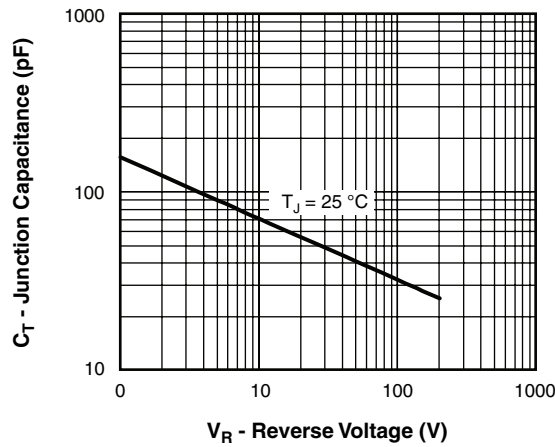


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

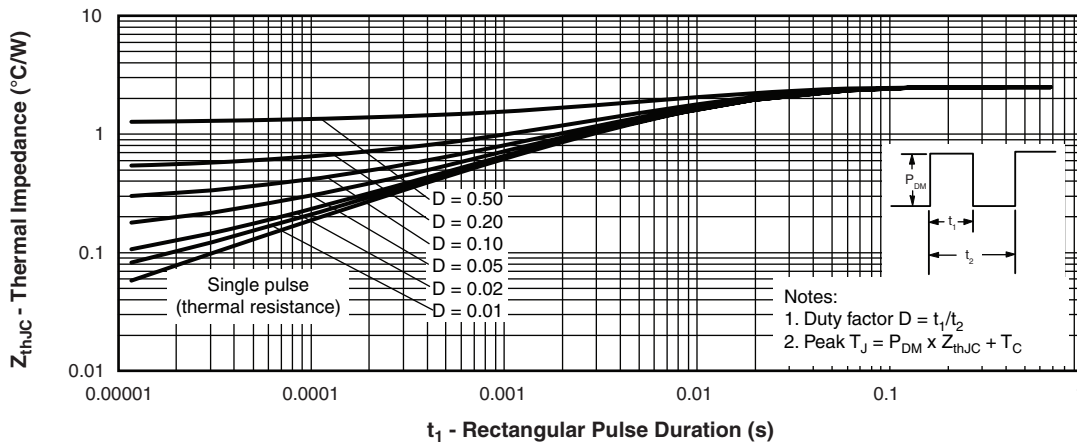


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

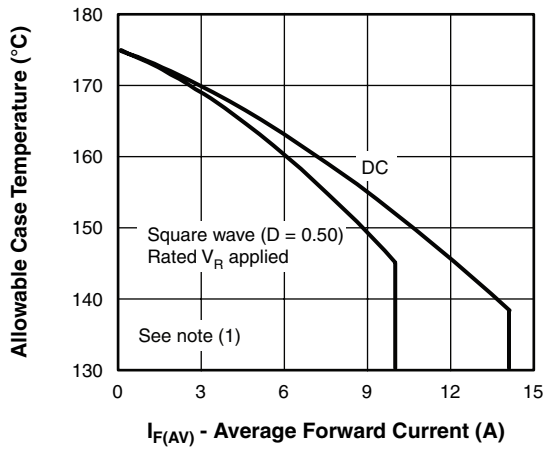


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

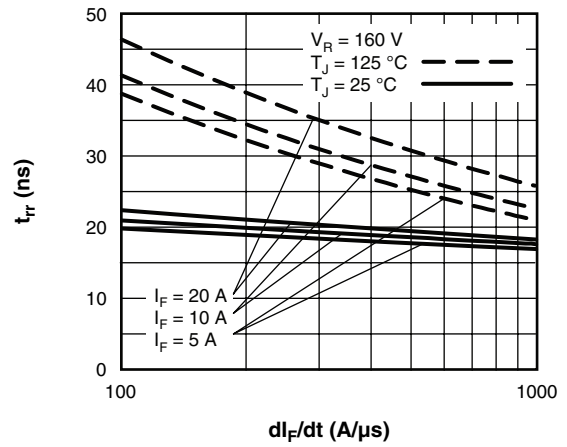


Fig. 7 - Typical Reverse Recovery Time vs.  $di_F/dt$

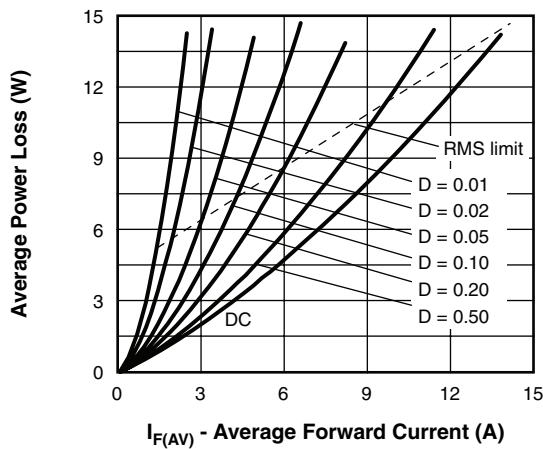


Fig. 6 - Forward Power Loss Characteristics

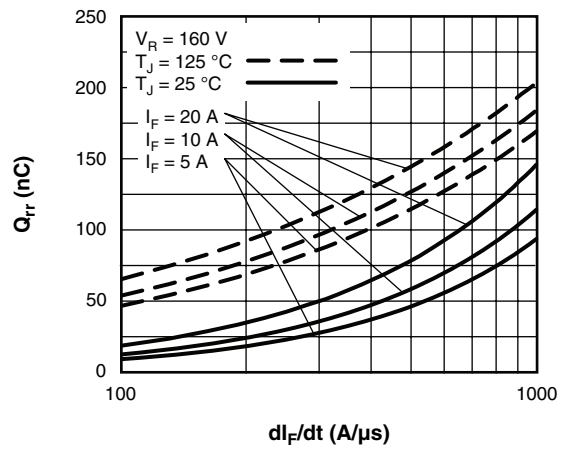


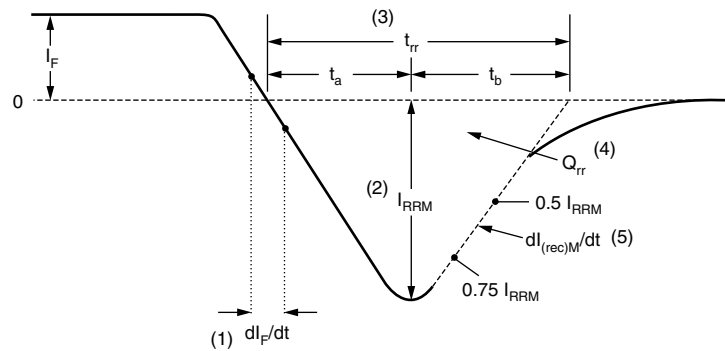
Fig. 8 - Typical Stored Charge vs.  $di_F/dt$

**Note**

- (1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  
 $Pd$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  
 $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = Rated  $V_R$



Fig. 9 - Reverse Recovery Parameter Test Circuit


 (1)  $dl_F/dt$  - rate of change of current through zero crossing

 (2)  $I_{RRM}$  - peak reverse recovery current

 (3)  $t_{rr}$  - reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through  $0.75 I_{RRM}$  and  $0.50 I_{RRM}$  extrapolated to zero current.

 (4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$  and  $I_{RRM}$ 

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

 (5)  $dl_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 10 - Reverse Recovery Waveform and Definitions

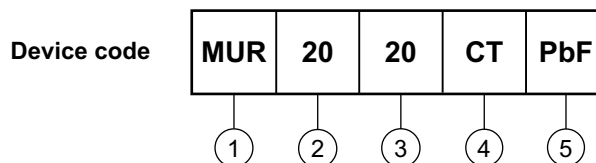
# MUR2020CTPbF

Vishay High Power Products

Ultrafast Rectifier,  
20 A FRED Pt™



## ORDERING INFORMATION TABLE



- 1** - Ultrafast MUR series
- 2** - Current rating (20 = 20 A)
- 3** - Voltage rating (20 = 200 V)
- 4** - CT = Center tap (dual)
- 5** -
  - None = Standard production
  - PbF = Lead (Pb)-free

Tube standard pack quantity: 50 pieces

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95222">http://www.vishay.com/doc?95222</a>
Part marking information	<a href="http://www.vishay.com/doc?95225">http://www.vishay.com/doc?95225</a>
SPIICE model	<a href="http://www.vishay.com/doc?95272">http://www.vishay.com/doc?95272</a>



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